

TO-5 HERMETIC CAN PACKAGE ACTIVE AREA $=4.48 \mathrm{~mm}^{2}$

## FEATURES

- High speed
- U.V. enhanced
- Low capacitance
- U.V. window


## DESCRIPTION

The PDU-C105 is a silicon, PIN planar diffused, U.V. enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-5 metal can with a U.V. transmitting window.

## APPLICATIONS

- Spectrometers
- Fluorescent analysers
- U.V. meters
- Colorimeters

ABSOLUTE MAXIMUM RATING (TA $=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS |
| :---: | :--- | :---: | :---: | :---: |
| $\mathrm{V}_{\text {вв }}$ | Reverse Voltage |  | 30 | V |
| $\mathrm{~T}_{\text {sta }}$ | Storage Temperature | -55 | +150 | $\circ$ |
| $\mathrm{~T}_{\circ}$ | Operating Temperature Range | -40 | +125 | $\circ$ |
| $\mathrm{~T}_{\mathrm{s}}$ | Soldering Temperature |  |  |  |
| $\mathrm{I}_{\mathrm{L}}$ | Light Current |  | +240 | $\circ$ |

*1/16 inch from case for 3 secs max

SPECTRALRESPONSE


ELECTRO-OPTICAL CHARACTERISTICS $\left(T A=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| SYMBOL | CHARACTERISTIC | TESTCONDITIONS | MIN | TYP | MAX | UNITS |
| :---: | :--- | :--- | :---: | :---: | :---: | :---: |
| Isc | Short Circuit Current | $\mathrm{H}=100 \mathrm{fc}, 2850 \mathrm{~K}$ | 40 | 56 |  | $\mu \mathrm{~A}$ |
| Id | Dark Current | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}$ |  | 1.0 | 5.0 | nA |
| RsH | Shunt Resistance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ | .25 | 1.0 |  | $\mathrm{G} \Omega$ |
| TC RsH | RSH Temp. Coefficient | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=10 \mathrm{mV}$ |  | -8 |  | $\% /{ }^{\circ} \mathrm{C}$ |
| C | Junction Capacitance | $\mathrm{H}=0, \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}^{* *}$ |  | 37 |  | pF |
| $\lambda$ range | Spectral Application Range | Spot Scan | 190 |  | 1100 | nm |
| R | Responsivity | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \lambda=254 \mathrm{~nm}$ | .12 | .18 |  | $\mathrm{~A} / \mathrm{W}$ |
| $\mathrm{V}_{\text {BR }}$ | Breakdown Voltage | $\mathrm{I}=10 \mu \mathrm{~A}$ | 15 | 25 |  | V |
| NEP | Noise Equivalent Power | $\mathrm{V}_{\mathrm{R}}=10 \mathrm{mV} @$ Peak |  | $1.3 \times 10^{-14}$ |  | $\mathrm{~W} / \sqrt{\mathrm{Hz}}$ |
| tr | Response Time | $\mathrm{RL}=1 \mathrm{~K} \Omega \mathrm{~V}_{\mathrm{R}}=5 \mathrm{~V}$ |  | 50 |  | nS |

Information inthis technical data sheet is believed to be correctand reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.**f $=1 \mathrm{MHz}$
[FORM NO. 100-PDU-C105 REV N/C]

